

Features

- Three quadrants Triac
- 600 to 800 V V_{DRM}/V_{RRM}

Applications

- General purpose AC inductive loads
- Motor control circuits
- Small home appliances

Description

Based on ST's Snubberless / logic level technology providing high commutation performances, the T4 series is suitable for use on AC inductive loads. They are recommended for applications using universal motors, electro valves, kitchen aid equipments, power tools, and dishwashers.

Table 1. Main characteristics

Symbol	Value	Unit
$I_{T(rms)}$	4	A
V_{DRM}, V_{RRM}	600 to 800	V
I_{GT}	5 to 35	mA

Table 2. Device summary

Symbol ⁽¹⁾	Marking
T405-xxxB	see Table 11
T405-xxxB-TR	
T405-xxxH	
T405-xxxT	
T410-xxxB	
T410-xxxB-TR	
T410-xxxH	
T410-xxxT	
T435-xxxB	
T435-xxxB-TR	
T435-xxxH	
T435-xxxT	

1. xxx = Voltage: 600 V, 700 V or 800 V (see [Table 10](#)).

1 Characteristics

Table 3. Absolute maximum ratings ($T_j = 25\text{ °C}$ unless otherwise stated)

Symbol	Parameter			Value	Unit
$I_{T(rms)}$	On-state rms current (full sine wave)	IPAK, DPAK, TO-220AB	$T_c = 110\text{ °C}$	4	A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C)	F = 50 Hz	t = 20 ms	30	A
		F = 60 Hz	t = 16.7 ms	31	
I^2t	I^2t value for fusing		$t_p = 10\text{ ms}$	5.1	A^2s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	F = 120 Hz	$T_j = 125\text{ °C}$	50	A/ μs
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu s$	$T_j = 125\text{ °C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125\text{ °C}$	1	W
T_{stg}	Storage junction temperature range			- 40 to +150	$^{\circ}C$
T_j	Operating junction temperature range			- 40 to +125	

Table 4. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise stated)

Symbol	Test conditions	Quadrant		Value			Unit
				T405	T410	T435	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 30\text{ }\Omega$	I - II - III	Max.	5	10	35	mA
V_{GT}	$V_D = 12\text{ V}$, $R_L = 30\text{ }\Omega$	I - II - III	Max.	1.3			V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$, $T_j = 125\text{ °C}$	I - II - III	Min.	0.2			V
$I_H^{(2)}$	$I_T = 100\text{ mA}$		Max.	10	15	35	mA
I_L	$I_G = 1.2 I_{GT}$	I - III	Max.	10	25	50	mA
		II	Max.	15	30	60	
dV/dt ⁽²⁾	$V_D = 67\% V_{DRM}$, gate open	$T_j = 125\text{ °C}$	Min.	20	40	400	V/ μs
(dI/dt) _c ⁽²⁾	(dV/dt) _c = 0.1 V/ μs	$T_j = 125\text{ °C}$	Min.	1.8	2.7		A/ms
	(dV/dt) _c = 10 V/ μs			0.9	2.0		
	(without snubber)					2.5	

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.
2. For both polarities of A2 referenced to A1

Table 5. Static characteristics

Symbol	Test conditions			Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 5.5 \text{ A}$, $t_p = 380 \text{ } \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.56	V
$V_{t0}^{(1)}$	Threshold voltage	$T_j = 125 \text{ }^\circ\text{C}$	Max.	0.89	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 125 \text{ }^\circ\text{C}$	Max.	120	m Ω
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	μA
		$T_j = 125 \text{ }^\circ\text{C}$		1	mA

1. For both polarities of A2 referenced to A1

Table 6. Thermal resistance

Symbol	Parameter		Value	Unit	
$R_{th(j-c)}$	Junction to case (AC)		IPAK, DPAK, TO-220AB	2.6	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient	$S^{(1)} = 0.5 \text{ cm}^2$	DPAK	70	$^\circ\text{C/W}$
	Junction to ambient		TO-220AB	60	$^\circ\text{C/W}$
				IPAK	100

1. S = Copper surface under tab.

Figure 1. Maximum power dissipation versus RMS on-state current (full cycle)

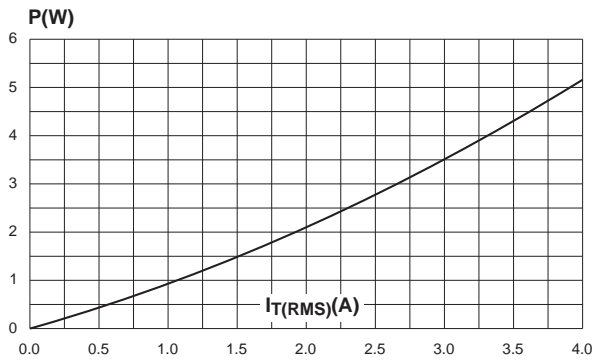


Figure 2. RMS on-state current versus case temperature (full cycle)

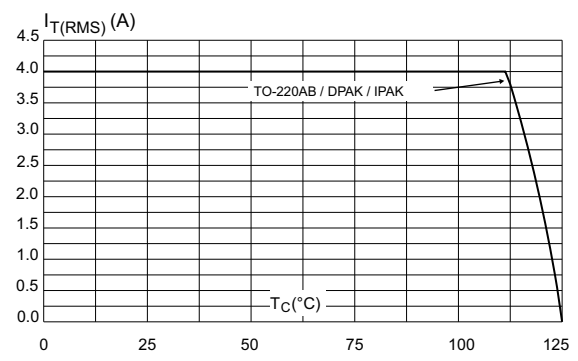


Figure 3. RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm) (full cycle)

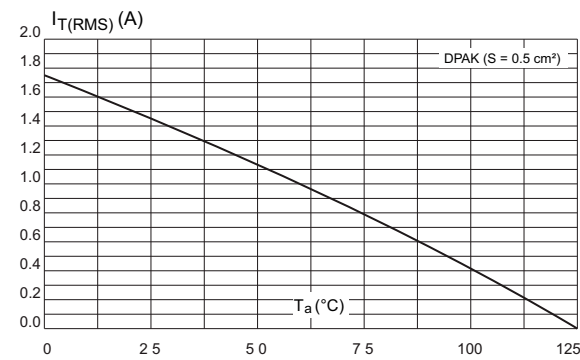


Figure 4. Relative variation of thermal impedance versus pulse duration



Figure 5. On-state characteristics (maximum values)

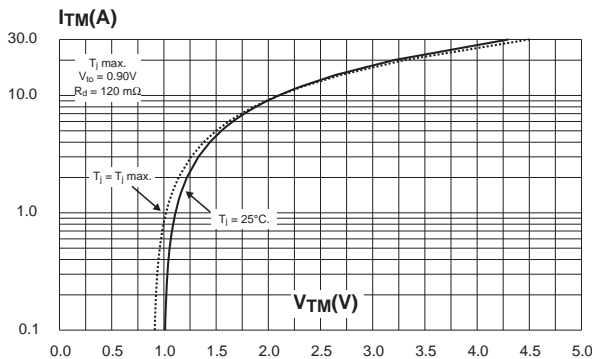


Figure 6. Surge peak on-state current versus number of cycles

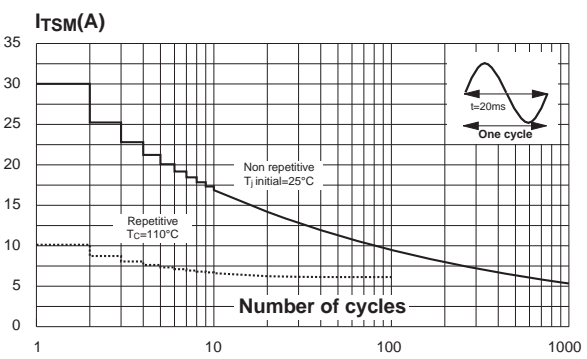


Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms



Figure 8. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)



Figure 9. Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values)

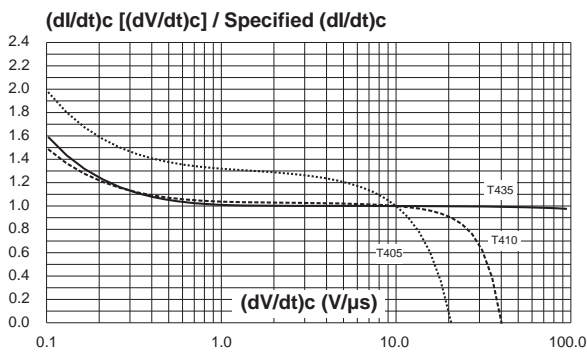


Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

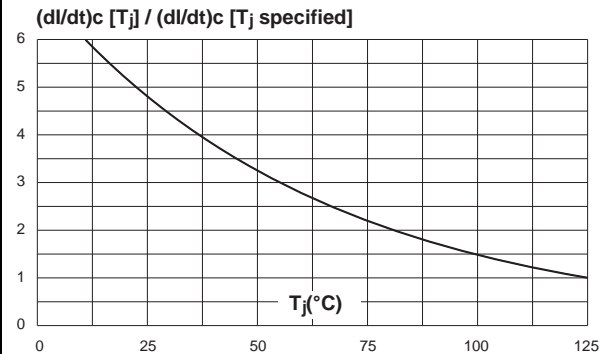
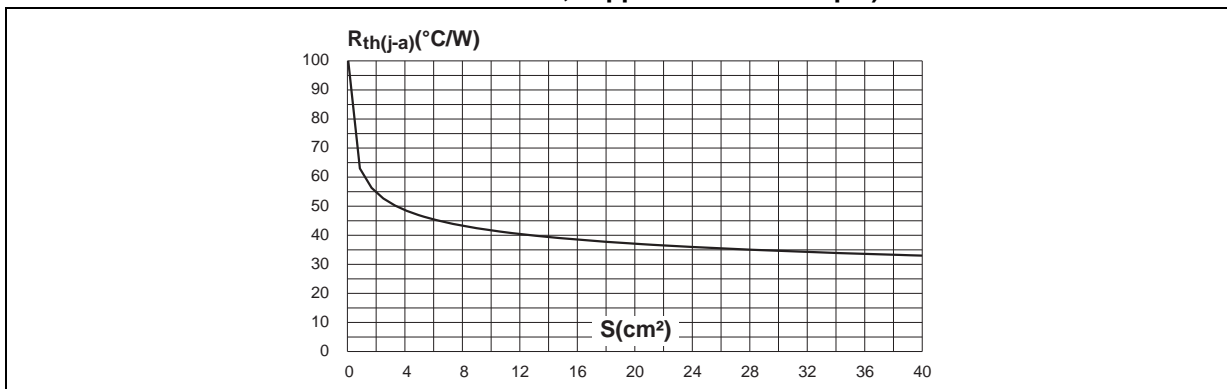


Figure 11. DPAK thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 μ m)



2 Package information

- Molding epoxy meets UL94, V0 and is halogen free
- Lead-free package
- Recommended torque: 0.4 to 0.6 N·m for TO-220AB

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 DPAK package information

Figure 12. DPAK package outline



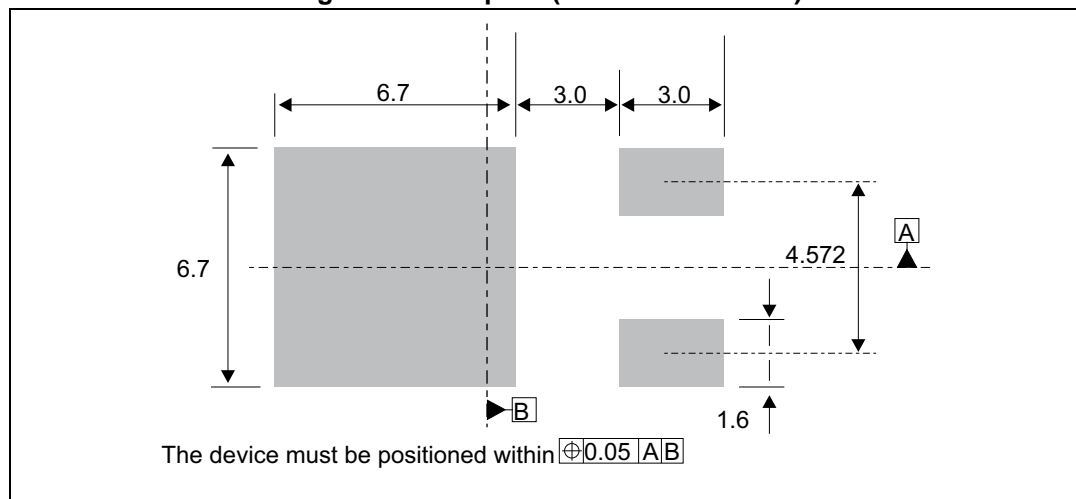
Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 7. DPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.18		2.40	0.086		0.0944
A1	0.9		1.10	0.035		0.0433
A2	0.03		0.23	0.0011		0.0090
b	0.64		0.90	0.0251		0.0354
b4	4.95		5.46	0.1948		0.2149
c	0.46		0.61	0.0181		0.0240
c2	0.46		0.60	0.0181		0.0236
D	5.97		6.22	0.2350		0.2448
D1	4.95			0.1948		
E	6.35		6.73	0.2500		0.2649
E1	4.32			0.1700		
e		2.286			0.09	
e1		4.572			0.18	
H	9.35		10.40	0.3681		0.4094
L	1.0		1.78	0.039		0.0700
L2			1.27			0.0500
L4	0.6		1.02	0.023		0.0401
V2	-8°		+8°	-8°		+8°

1. Inch dimensions are only for reference

Figure 13. Footprint (dimensions in mm)



2.2 IPAK package information

Figure 14. IPAK package outline



Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 8. IPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.0866		0.0945
A1	0.90		1.10	0.0354		0.0433
b	0.64		0.90	0.0252		0.0354
b2			0.95			0.0374
b4	5.20		5.43	0.2047		0.2138
c	0.45		0.60	0.0177		0.0236
c2	0.46		0.60	0.0181		0.0236
D	6		6.20	0.2362		0.2441
E	6.40		6.65	0.2520		0.2618
e		2.28			0.0898	
e1	4.40		4.60	0.1732		0.1811
H		16.10			0.6339	
L	9		9.60	0.3543		0.3780
L1	0.8		1.20	0.0315		0.0472
L2		0.80	1.25		0.0315	0.0492
V1		10°			10°	

1. Inch dimensions are only for reference

2.3 TO-220AB (insulated and non-insulated) information

Figure 15. TO-220AB (insulated and non-insulated) package outline



Table 9. TO-220AB (insulated and non-insulated) package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6259
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5511
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0519
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0192		0.0275
c2	2.40		2.72	0.0944		0.1070
e	2.40		2.70	0.0944		0.1062
F	6.20		6.60	0.2440		0.2598
ØI	3.73		3.88	0.1468		0.1527
I4	15.80	16.40	16.80	0.6220	0.6456	0.6614
L	2.65		2.95	0.1043		0.1161
I2	1.14		1.70	0.0448		0.0669
I3	1.14		1.70	0.0448		0.0669
M		2.60			0.1023	

1. Inch dimensions are only for reference

3 Ordering information

Figure 16. Order information scheme



Table 10. Product selector

Part number	Voltage (xxx)			Sensitivity	Type	Package
	600 V	700 V	800 V			
T405-xxxB	X			5 mA	Logic level	DPAK
T405-xxxB-TR	X	X	X	5 mA	Logic level	DPAK
T405-xxxH	X		X	5 mA	Logic level	IPAK
T405-xxxT	X			5 mA	Logic level	TO-220AB
T410-xxxB	X			10 mA	Logic level	DPAK
T410-xxxB-TR	X		X	10 mA	Logic level	DPAK
T410-xxxH	X		X	10 mA	Logic level	IPAK
T410-xxxT	X	X	X	10 mA	Logic level	TO-220AB
T435-xxxB	X			35 mA	Snubberless	DPAK
T435-xxxB-TR	X	X	X	35 mA	Snubberless	DPAK
T435-xxxH	X		X	35 mA	Snubberless	IPAK
T435-xxxT	X		X	35 mA	Snubberless	TO-220AB

Blank = Unavailable

Table 11. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode		
T405-600B	T4 0560	DPAK	0.3 g	75	Tube		
T410-600B	T4 1060						
T435-600B	T4 3560						
T405-600B-TR	T4 0560			2500	Tape and reel		
T410-600B-TR	T4 1060						
T435-600B-TR	T4 3560						
T405-700B-TR	T4 0570						
T435-700B-TR	T4 3570						
T405-800B-TR	T4 0580						
T410-800B-TR	T4 1080			IPAK	0.4 g	75	Tube
T435-800B-TR	T4 3580						
T405-600H	T4 0560						
T410-600H	T4 1060						
T435-600H	T4 3560						
T405-800H	T4 0580						
T410-800H	T4 1080	TO-220AB	2.3 g	50	Tube		
T435-800H	T4 3580						
T405-600T	T405-600T						
T410-600T	T410-600T						
T435-600T	T435-600T						
T410-700T	T410-700T						
T410-800T	T410-800T						
T435-800T	T435-800T						

4 Revision history

Table 12. Document revision history

Date	Revision	Changes
Jun-2003	2	Last updated.
25-Mar-2005	3	Layout updated, No content change.
25-Jan-2006	4	Markings changed in <i>Table 12</i> .
14-May-2014	5	Updated DPAK and IPAK package information and reformatted to current standard.
11-Feb-2015	6	Updated package silhouettes in cover page.
1-Apr-2016	7	Removed ISOWATT-220AB package information.
05-Oct-2016	8	Updated <i>Table 3</i> and <i>Table 11</i> . Updated <i>Figure 2</i> and <i>Figure 4</i> .
14-Nov-2016	9	Updated <i>Table 1</i> .

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2016 STMicroelectronics – All rights reserved



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.